NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

Rev. 3 — 28 June 2011

Product data sheet

1. Product profile

1.1 General description

NPN/PNP resistor-equipped transistors.

| Table 1. | Product | overview |
|----------|---------------|-----------|
| | 1 I O G G O C | 010111011 |

| Type number | r Package | | Package | | PNP/PNP | NPN/NPN |
|-------------|-----------|-------|------------|------------|---------|---------|
| | NXP | JEITA | complement | complement | | |
| PEMD16 | SOT666 | - | PEMB16 | PEMH16 | | |
| PUMD16 | SOT363 | SC-88 | PUMB16 | PUMH16 | | |

1.2 Features and benefits

- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place cost

1.3 Applications

- Low current peripheral driver
- Control of IC inputs
- Replacement of general-purpose transistors in digital applications

1.4 Quick reference data

Table 2. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|---------------------------|------------|------|-----|------|------|
| V _{CEO} | collector-emitter voltage | open base | - | - | 50 | V |
| Ι _Ο | output current | | - | - | 100 | mA |
| R1 | bias resistor 1 (input) | | 15.4 | 22 | 28.6 | kΩ |
| R2/R1 | bias resistor ratio | | 1.7 | 2.1 | 2.6 | |



| | 2 3 006aaa143

NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

2. Pinning information

| Table 3. | Pinning | | |
|----------|------------------------|--------------------|----------------|
| Pin | Description | Simplified outline | Graphic symbol |
| 1 | GND (emitter) TR1 | | |
| 2 | input (base) TR1 | 6 5 4 | |
| 3 | output (collector) TR2 | | |
| 4 | GND (emitter) TR2 | | |
| 5 | input (base) TR2 | | |
| 6 | output (collector) TR1 | 001aab555 | |

3. Ordering information

| Table 4. Orde | Table 4. Ordering information | | | |
|---------------|---------------------------------------|--|---------|--|
| Type number | Package | | | |
| | Name | Description | Version | |
| PEMD16 | - | plastic surface-mounted package; 6 leads | SOT666 | |
| PUMD16 | SC-88 | plastic surface-mounted package; 6 leads | SOT363 | |

4. Marking

| Table 5. Marking codes | |
|------------------------|-----------------------------|
| Type number | Marking code ^[1] |
| PEMD16 | 5H |
| PUMD16 | D1* |

[1] * = placeholder for manufacturing site code

NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

5. Limiting values

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|--------------------------------|------------------------------|-----------------|------|------|
| Per transis | stor; for the PNP transistor v | with negative polari | t y | | |
| V _{CBO} | collector-base voltage | open emitter | - | 50 | V |
| V _{CEO} | collector-emitter voltage | open base | - | 50 | V |
| V _{EBO} | emitter-base voltage | open collector | - | 5 | V |
| VI | input voltage TR1 | | | | |
| | positive | | - | +40 | V |
| | negative | | - | -7 | V |
| | input voltage TR2 | | | | |
| | positive | | - | +7 | V |
| | negative | | - | -40 | V |
| lo | output current | | - | 100 | mA |
| I _{CM} | peak collector current | | - | 100 | mA |
| P _{tot} | total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | | | |
| | SOT363 | | <u>[1]</u> - | 200 | mW |
| | SOT666 | | <u>[1][2]</u> _ | 200 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | - | 150 | °C |
| T _{amb} | ambient temperature | | -65 | +150 | °C |
| Per device |) | | | | |
| P _{tot} | total power dissipation | $T_{amb} \leq 25 ~^{\circ}C$ | | | |
| | SOT363 | | <u>[1]</u> - | 300 | mW |
| | SOT666 | | [1][2] _ | 300 | mW |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

6. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|---|-------------|-----------------|-----|-----|------|
| Per transi | stor | | | | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | | | | |
| | SOT363 | | [1] - | - | 625 | K/W |
| | SOT666 | | <u>[1][2]</u> _ | - | 625 | K/W |
| Per device | 9 | | | | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | | | | |
| | SOT363 | | [1] - | - | 416 | K/W |
| | SOT666 | | <u>[1][2]</u> _ | _ | 416 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

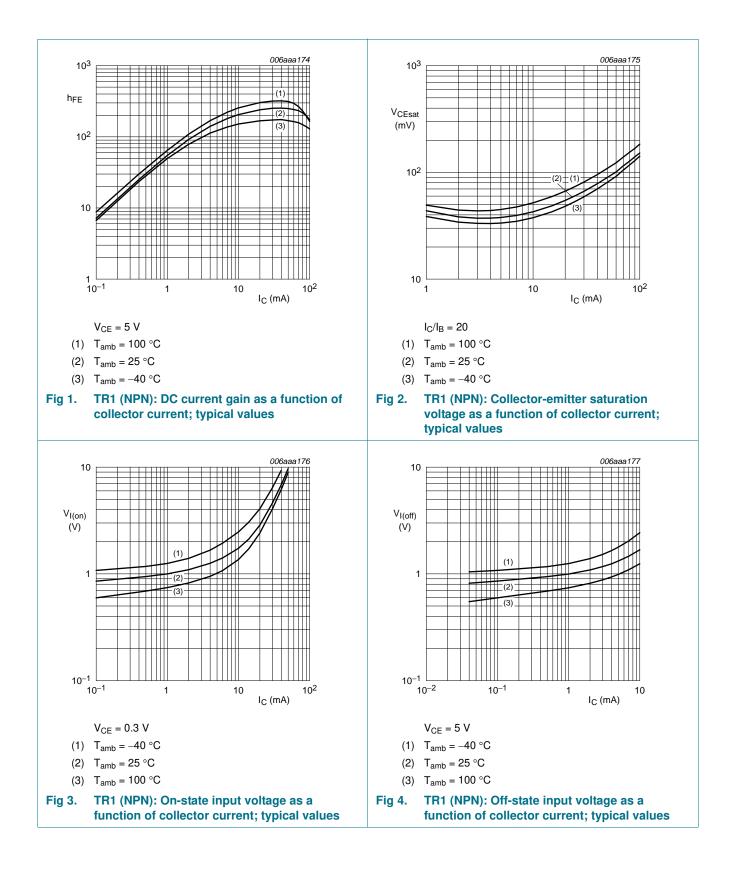
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|--------------------------------------|--|------|-----|------|------|
| - | | nsistor with negative polarit | у | | | |
| I _{CBO} | collector-base cut-off current | $V_{CB} = 50 \text{ V}; \text{ I}_{E} = 0 \text{ A}$ | - | - | 100 | nA |
| I _{CEO} | CEO collector-emitter | $V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0 \text{ A}$ | - | - | 1 | μA |
| | cut-off current | $\label{eq:VCE} \begin{array}{l} V_{CE} = 30 \ V; \ I_{B} = 0 \ A; \\ T_{j} = 150 \ ^{\circ}C \end{array}$ | - | - | 50 | μA |
| I _{EBO} | emitter-base cut-off current | $V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$ | - | - | 120 | μA |
| h _{FE} | DC current gain | $V_{CE} = 5 \text{ V}; I_{C} = 5 \text{ mA}$ | 80 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | $I_{C} = 10 \text{ mA}; I_{B} = 0.5 \text{ mA}$ | - | - | 150 | mV |
| V _{I(off)} | off-state input voltage | $V_{CE} = 5 \text{ V}; \text{ I}_{C} = 100 \mu\text{A}$ | - | 0.8 | 0.5 | V |
| V _{I(on)} | on-state input voltage | $V_{CE} = 0.3 \text{ V}; I_{C} = 2 \text{ mA}$ | 2 | 1.1 | - | V |
| R1 | bias resistor 1 (input) | | 15.4 | 22 | 28.6 | kΩ |
| R2/R1 | bias resistor ratio | | 1.7 | 2.1 | 2.6 | |
| Cc | collector capacitance | $\label{eq:VCB} \begin{array}{l} V_{CB} = -10 \ V; \\ I_E = i_e = 0 \ A; \ f = 1 \ MHz \end{array}$ | | | | |
| | TR1 (NPN) | | - | - | 2.5 | pF |
| | TR2 (PNP) | | - | - | 3 | pF |

PEMD16_PUMD16 Product data sheet

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PEMD16; PUMD16

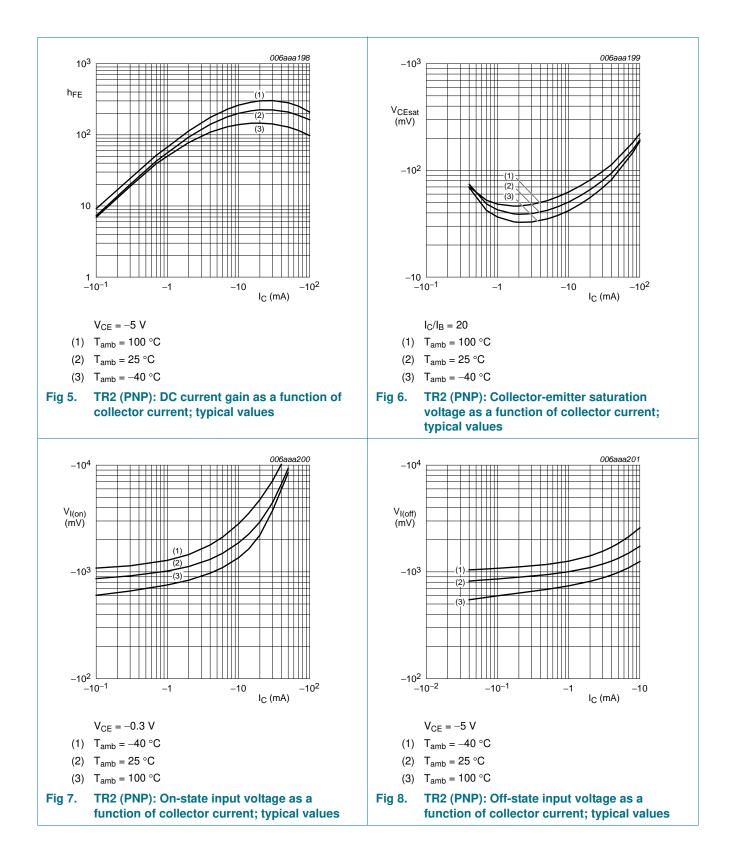
NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω



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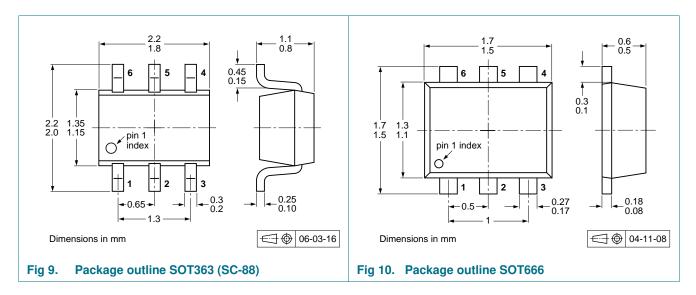
PEMD16; PUMD16

NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω



NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

8. Package outline



9. Packing information

Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code. [1]

| Type number | Package | Description | | Packin | g quanti | ty |
|-------------|---------|------------------------------------|-----|--------|----------|-------|
| | | | | 3000 | 4000 | 10000 |
| PEMD16 | SOT666 | 4 mm pitch, 8 mm tape and reel | | - | -115 | - |
| PUMD16 | SOT363 | 4 mm pitch, 8 mm tape and reel; T1 | [2] | -115 | - | -135 |
| | | 4 mm pitch, 8 mm tape and reel; T2 | [3] | -125 | - | -165 |

[1] For further information and the availability of packing methods, see Section 12.

[2] T1: normal taping

[3] T2: reverse taping

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10. Revision history

| Table 10. Revision his | tory | | | | | |
|------------------------|---|---|---------------|-------------------|--|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
| PEMD16_PUMD16 v.3 | 20110628 | Product data sheet | - | PEMD16_PUMD16 v.2 | | |
| Modifications: | guidelines of I | this document has been re NXP Semiconductor. ave been adapted to the ne | c , | · | | |
| | Figure 9 "Package outline SOT363 (SC-88)" is updated. | | | | | |
| | Section 11 "Le | egal information" is updated | d. | | | |
| PEMD16_PUMD16 v.2 | 20050607 | Product data sheet | - | PUMD16 v.1 | | |
| PUMD16 v.1 | 20031022 | Product specification | - | - | | |
| | | | | | | |

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11. Legal information

11.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
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PEMD16_PUMD16
Product data sheet

NPN/PNP resistor-equipped transistors; R1 = 22 k Ω , R2 = 47 k Ω

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